

Date: - 9 Jul, 2004

Data Sheet Issue:- 1

# Rectifier Diode Types W2820V#360 to W2820V#450

Old Type No.: SW36-45C/FXC1100

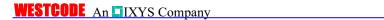
### **Absolute Maximum Ratings**

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
$V_{RRM}$	Repetitive peak reverse voltage, (note 1)	3600-4500	V
$V_{RSM}$	Non-repetitive peak reverse voltage, (note 1)	3700-4600	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
I <sub>F(AV)M</sub>	Maximum average forward current, T <sub>sink</sub> =55°C, (note 2)	2820	Α
$I_{F(AV)M}$	Maximum average forward current. T <sub>sink</sub> =100°C, (note 2)	1887	Α
$I_{F(AV)M}$	Maximum average forward current. T <sub>sink</sub> =100°C, (note 3)	1101	Α
I <sub>F(RMS)M</sub>	Nominal RMS forward current, T <sub>sink</sub> =25°C, (note 2)	5262	Α
I <sub>F(d.c.)</sub>	D.C. forward current, T <sub>sink</sub> =25°C, (note 4)	4350	Α
I <sub>FSM</sub>	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>m</sub> =60%V <sub>RRM</sub> , (note 5)	26.2	kA
I <sub>FSM2</sub>	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>m</sub> ≤10V, (note 5)	28.8	kA
I <sup>2</sup> t	I <sup>2</sup> t capacity for fusing t <sub>p</sub> =10ms, V <sub>m</sub> =60%V <sub>RRM</sub> , (note 5)	3.43×10 <sup>6</sup>	A <sup>2</sup> s
I <sup>2</sup> t	I²t capacity for fusing t <sub>p</sub> =10ms, V <sub>m</sub> ≤10V, (note 5)	4.15×10 <sup>6</sup>	A <sup>2</sup> s
T <sub>j op</sub>	Operating temperature range	-40 to +160	°C
T <sub>stg</sub>	Storage temperature range	-40 to +160	°C

#### Notes:-

- 1) De-rating factor of 0.13% per °C is applicable for T<sub>j</sub> below 25°C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, 160°C T<sub>i</sub> initial.



# **Characteristics**

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
$V_{FM}$	Maximum peak forward voltage	-	-	2.3	I <sub>TM</sub> =6800A	V
$V_{FM}$	Maximum peak forward voltage	-	-	2.6	I <sub>TM</sub> =8460A	V
$V_{T0}$	Threshold voltage	-	-	1.3		V
r <sub>T</sub>	Slope resistance	-	-	0.147		mΩ
I <sub>RRM</sub>	Peak reverse current	-	-	60	Rated V <sub>RRM</sub>	mA
Q <sub>rr</sub>	Recovered charge	-	7400	-		μC
Q <sub>ra</sub>	Recovered charge, 50% Chord	-	4000	4600	I <sub>TM</sub> =1000A, t <sub>p</sub> =1000μs, di/dt=10A/μs,	μC
I <sub>rr</sub>	Reverse recovery current	-	190	-	V <sub>r</sub> =50V	Α
t <sub>rr</sub>	Reverse recovery time, 50% Chord	-	42	-		μs
Б		-	-	0.016	Double side cooled	K/W
$R_{thJK}$	Thermal resistance, junction to heatsink	-	-	0.032	Single side cooled	K/W
F	Mounting force	27	-	34		kN
\A/		-	1000	-	Outline Options VC	
Wt	Weight	-	800	-	Outline Options VF	g

#### Notes:-

- 1) Unless otherwise indicated  $T_j=160$  °C.
- 2) For other clamp forces, please consult factory.



# **Notes on Ratings and Characteristics**

# 1.0 Voltage Grade Table

Voltage Grade	V <sub>DRM</sub> V <sub>DSM</sub> V <sub>RRM</sub>	V <sub>RSM</sub> V	V <sub>D</sub> V <sub>R</sub> DC V
36	3600	3700	1900
38	3800	3900	1950
40	4000	4100	2000
42	4200	4300	2040
44	4400	4500	2080
45	4500	4600	2120

#### 2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

# 3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T<sub>j</sub> below 25°C.

#### 4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

#### 5.0 Computer Modelling Parameters

### 5.1 Device Dissipation Calculations

$$I_{\scriptscriptstyle AV} = \frac{-V_{\scriptscriptstyle T0} + \sqrt{{V_{\scriptscriptstyle T0}}^2 + 4 \cdot \mathit{ff}^2 \cdot \mathit{r}_{\scriptscriptstyle T} \cdot W_{\scriptscriptstyle AV}}}{2 \cdot \mathit{ff}^2 \cdot \mathit{r}_{\scriptscriptstyle T}} \qquad \qquad \text{and:} \qquad W_{\scriptscriptstyle AV} = \frac{\Delta T}{R_{\scriptscriptstyle th}} \\ \Delta T = T_{\scriptscriptstyle f \, \rm max} - T_{\scriptscriptstyle K}$$

Where  $V_{T0}$ =1.3V,  $r_T$ =0.147 $m\Omega$ ,

 $R_{\it th}$  = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance					
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.	
Square wave Double Side Cooled	0.01576	0.01487	0.01429	0.01328	
Square wave Single Side Cooled	0.03399	0.03348	0.03300	0.03174	
Sine wave Double Side Cooled	0.01507	0.01429	0.01351		
Sine wave Single Side Cooled	0.03371	0.03318	0.03246		

Form Factors					
Conduction Angle 6 phase (60°) 3 phase (120°) ½ wave (180°) d.c.					
Square wave	2.449	1.732	1.414	1	
Sine wave	2.778	1.879	1.57		



#### 5.2 Calculating V<sub>F</sub> using ABCD Coefficients

The on-state characteristic I<sub>F</sub> vs. V<sub>F</sub>, on page 6 is represented in two ways;

- (i) the well established  $V_{T0}$  and  $r_T$  tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V<sub>F</sub> in terms of I<sub>F</sub> given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for  $V_F$  agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	160°C Coefficients
Α	0.82003623	0.489599427
В	0.03242465	0.06173783
С	9.876×10 <sup>-5</sup>	1.50996×10 <sup>-4</sup>
D	3.28948×10 <sup>-3</sup>	2.896029×10 <sup>-3</sup>

# 5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

Where p = 1 to n, n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

r, = Thermal resistance at time t.

 $r_p$  = Amplitude of  $p_{th}$  term.

 $\tau_p$  = Time Constant of  $r_{th}$  term.

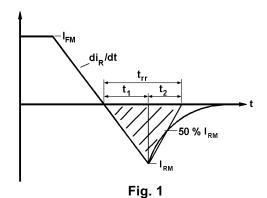
The coefficients for this device are shown in the tables below:

	D.C. Single Side Cooled				
Term 1 2					
r <sub>p</sub>	0.54145	2.62145			
$ au_{\mathcal{P}}$	0.07599	0.03111			

D.C. Double Side Cooled					
Term	1	2	3	4	
rp	0.06465	0.04241	0.02065	5.09×10 <sup>-3</sup>	
$ au_{\mathcal{P}}$	0.29708	0.10877	0.04414	2.95×10 <sup>-3</sup>	

# 6.0 Reverse recovery ratings

(i) Q<sub>ra</sub> is based on 50% I<sub>rm</sub> chord as shown in Fig. 1



(ii) Q<sub>rr</sub> is based on a 150µs integration time i.e.

$$Q_{rr} = \int_{0}^{150\,\mu s} i_{rr}.dt$$

(iii) 
$$K Factor = \frac{t_1}{t_2}$$

#### **Curves**

Figure 1 - Forward characteristics of Limit device

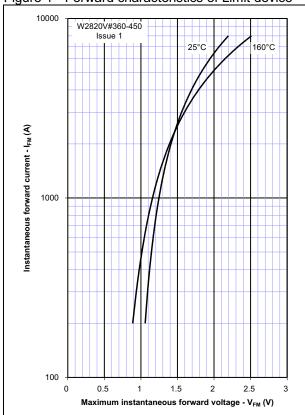


Figure 2 - Transient thermal impedance

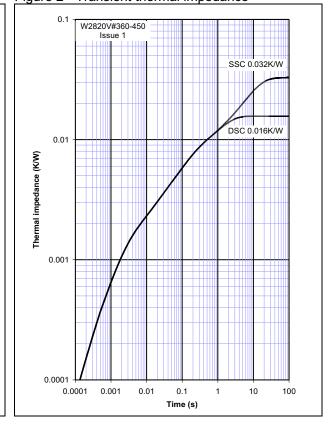


Figure 3 - Maximum surge Rating

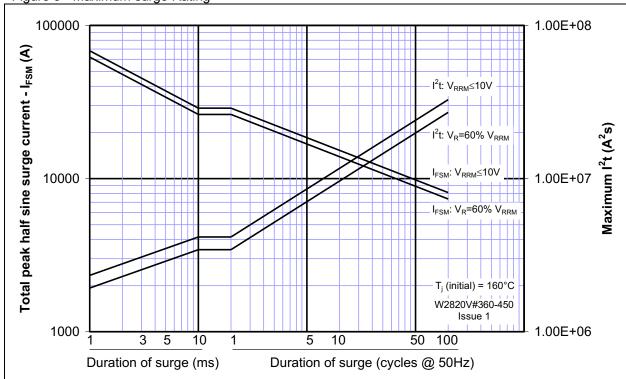


Figure 4 - Total recovered charge, Q<sub>rr</sub>

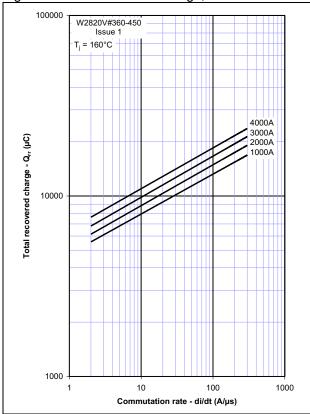


Figure 5 - Recovered charge, Q<sub>ra</sub> (50% chord)

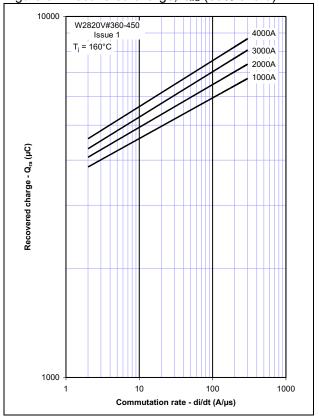


Figure 6 - Peak reverse recovery current, Irm

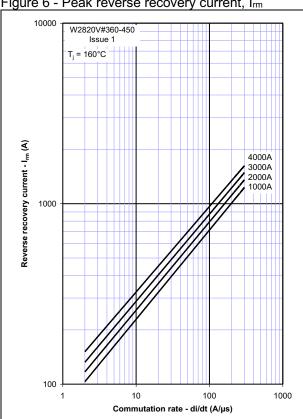


Figure 7 - Maximum recovery time, t<sub>rr</sub> (50% chord)

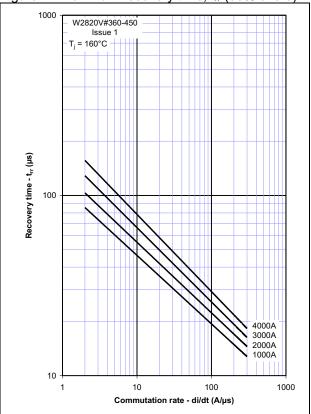


Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

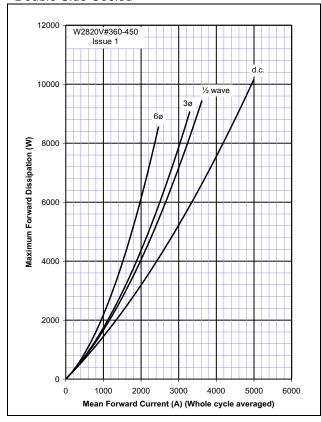


Figure 10 – Forward current vs. Power dissipation – Single Side Cooled

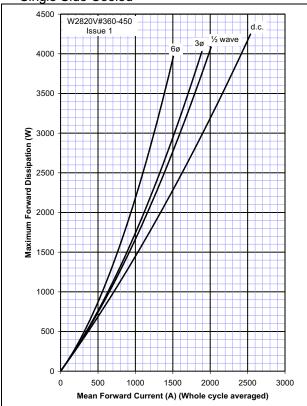


Figure 9 – Forward current vs. Heatsink temperature - Double Side Cooled

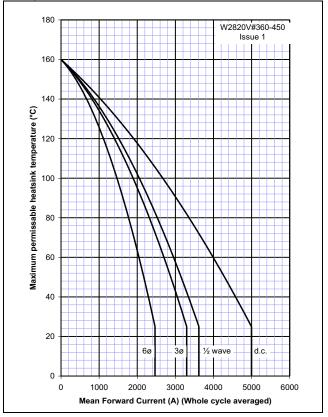
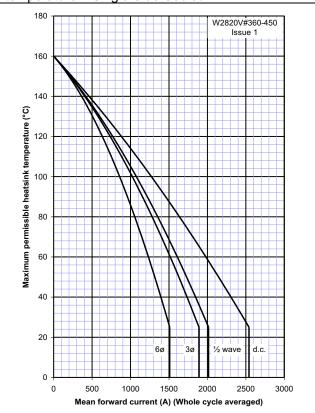
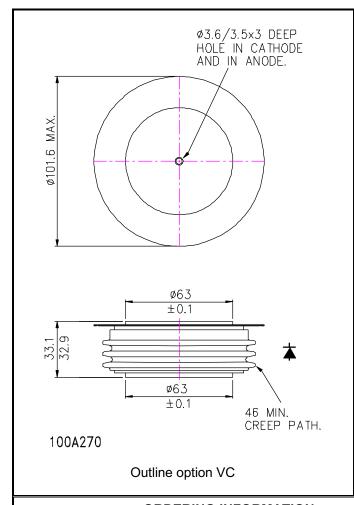
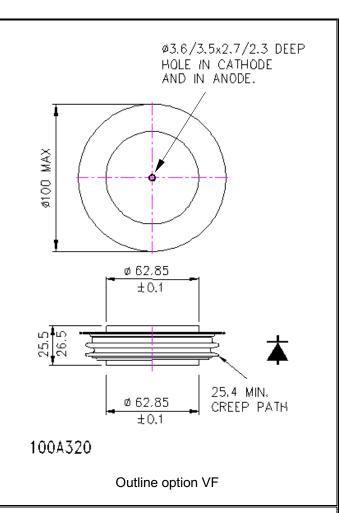


Figure 11 – Forward current vs. Heatsink temperature – Single Side Cooled



# **Outline Drawing & Ordering Information**





(Please quote 10 digit code as below)		
<b>* *</b>	0	
Voltage code V <sub>RRM</sub> /100 36-45	Fixed turn-off time code	
	V <sub>RRM</sub> /100	

Order code: W2820VC380 - 3800V V<sub>RRM</sub>, 33.1mm clamp height capsule.

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